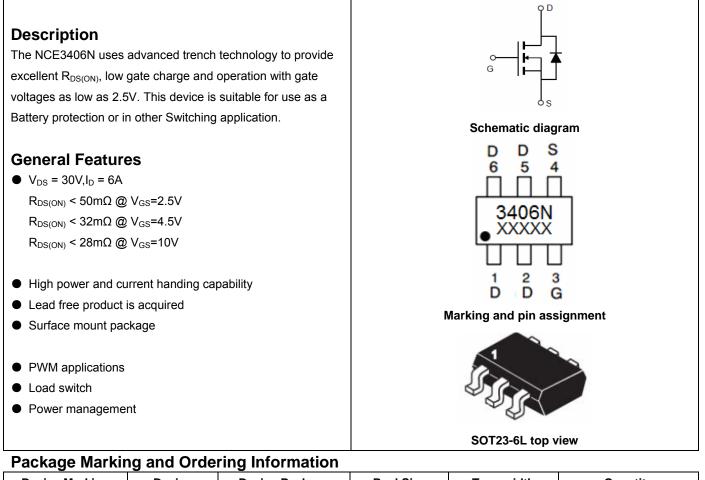


NCE N-Channel Enhancement Mode Power MOSFET



Device Marking	Device	Device Package	Reel Size	Tape width	Quantity	
3406N	NCE3406N	SOT23-6L	Ø180mm	8 mm	3000 units	

Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

5 ()			
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	30	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	I _D	6	A
Drain Current-Pulsed (Note 1)	I _{DM}	30	A
Maximum Power Dissipation	PD	2.0	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C
Thermal Characteristic		•	•

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	62.5	°C/W

Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	30	33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V	-	-	±100	nA



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	0.7	0.9	1.4	V
		V _{GS} =2.5V, I _D =4A	-	27	50	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =5A	-	24	32	mΩ
		V _{GS} =10V, I _D =6A	-	20.5	28	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =6A	10	-	-	S
Dynamic Characteristics (Note4)						•
Input Capacitance	C _{lss}		-	820	-	PF
Output Capacitance	Coss	V_{DS} =15V, V_{GS} =0V,	-	99	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	77	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t _{d(on)}		-	3.3	-	nS
Turn-on Rise Time	tr	V_{DD} =15V, R _L =2.5 Ω	-	4.8	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{GEN} =3 Ω	-	26	-	nS
Turn-Off Fall Time	t _f		-	4	-	nS
Total Gate Charge	Qg	V _{DS} =15V,I _D =6A,	-	9.5	-	nC
Gate-Source Charge	Q _{gs}		-	1.5	-	nC
Gate-Drain Charge	Q _{gd}	V_{GS} =4.5V	-	3	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =6A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	6	А

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

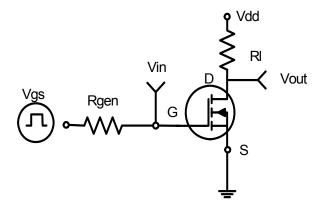


Figure 1:Switching Test Circuit

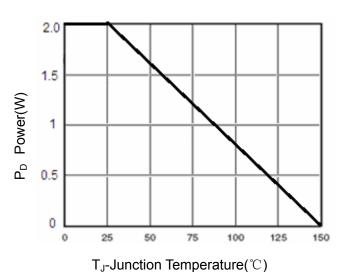
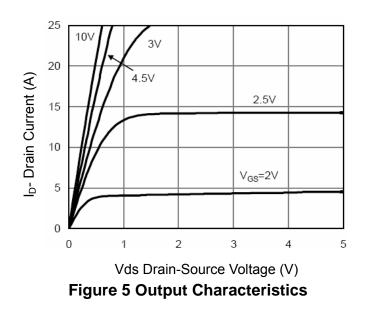


Figure 3 Power Dissipation



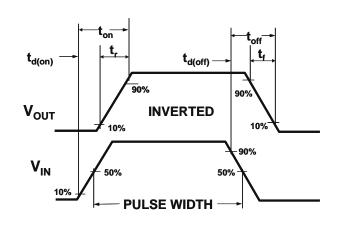
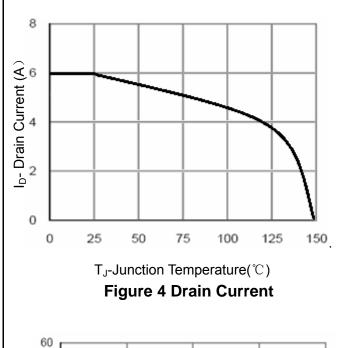


Figure 2:Switching Waveforms



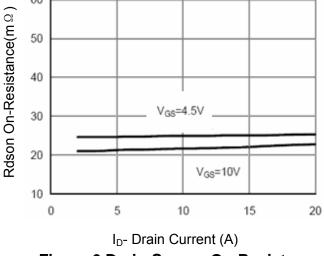


Figure 6 Drain-Source On-Resistance



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NCE3406N

V_{GS}=10∨

125

150

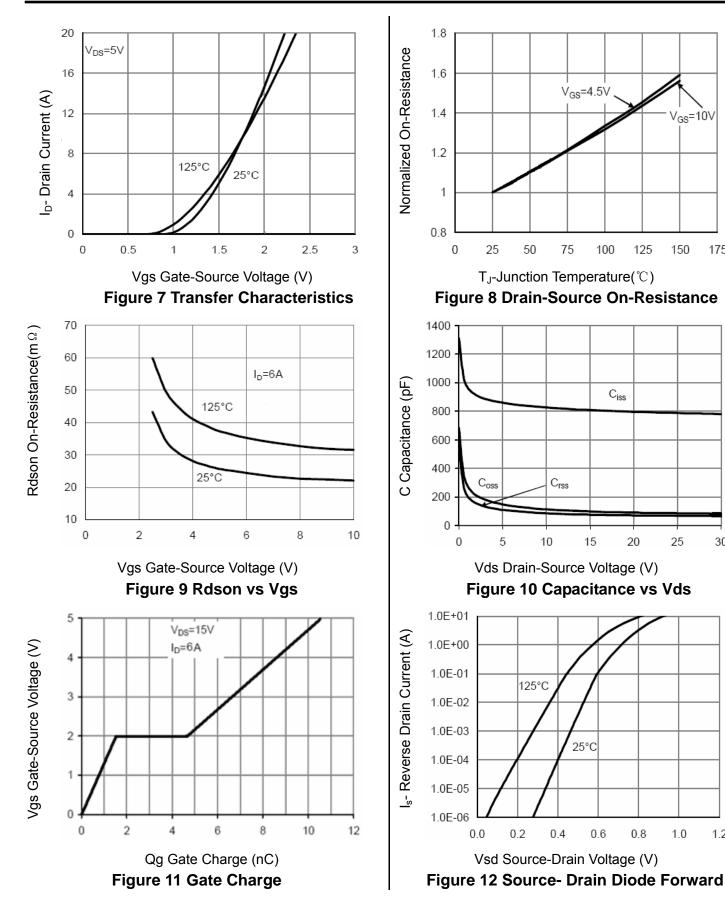
25

1.0

1.2

30

175





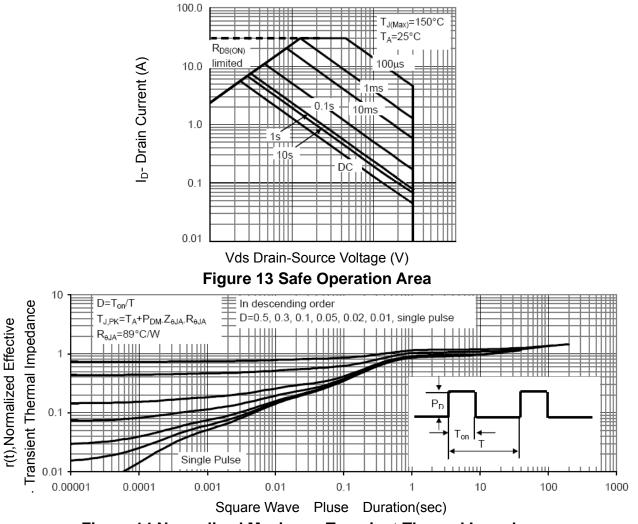
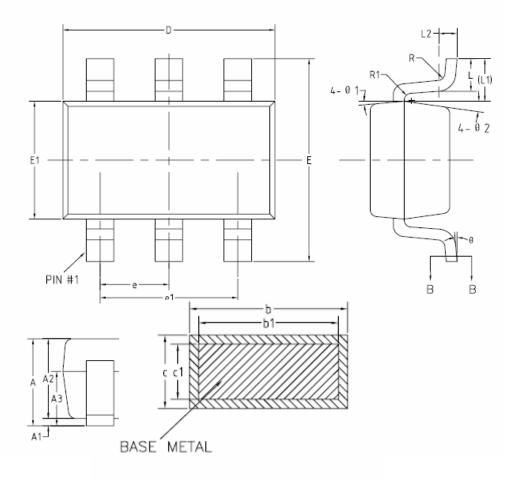


Figure 14 Normalized Maximum Transient Thermal Impedance



SOT23-6L Package Information

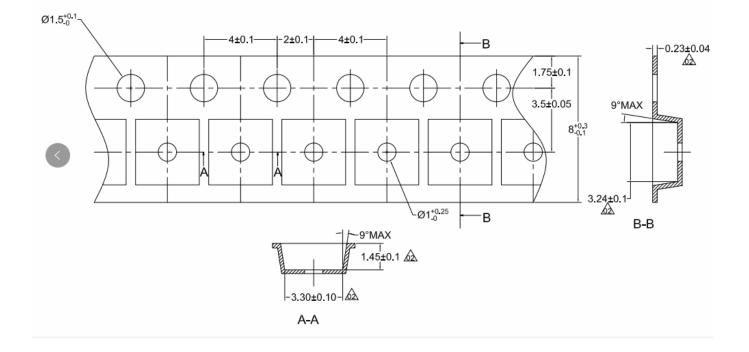


SYMBOL	MIN	NOM	MAX
A	-	-	1.45
A1	0	—	0.15
A2	0.90	1.10	1.30
A3	0.60	0.65	0.70
b	0.39	—	0.49
b1	0.38	0.40	0.45
с	0.12	-	0.19
c1	0.11	0.13	0.15
D	2.85	2.95	3.05
E	2.60	2.80	3.00
E1	1.55	1.65	1.75
е	0.85	0.95	1.05
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1		0.59REF	
L2		0.25BSC	
R	0.05	-	-
R1	0.05	-	0.20
θ	0*	-	8'
θ 1	8*	10°	12*
θ2	8*	10°	12°

COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)



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